

Subsolidus phase relationships of the $\text{BaO-R}_2\text{O}_3\text{-CuO}_z$ ($\text{R} = \text{Tm}$ and Yb) systems under carbonate-free conditions at $p_{\text{O}_2} = 100$ Pa, and $T = 750$ °C and 810 °C

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Abstract

For applications of phase equilibria to coated conductor processing, phase diagrams constructed under carbonate-free conditions should be employed. Using special apparatus and a procedure for preparing carbonate-free precursors based on BaO, phase diagrams of the $\text{BaO-Tm}_2\text{O}_3\text{-CuO}_z$ and $\text{BaO-Yb}_2\text{O}_3\text{-CuO}_z$ systems were determined at 100 Pa (0.1% O_2 by volume, 750 °C and 810 °C). The $\text{BaO-Yb}_2\text{O}_3\text{-CuO}_z$ system exhibits different features as compared to the Tm-analog. For example, the Yb-system does not contain the $\text{Ba}_4\text{RCu}_3\text{O}_{8.5+z}$ phase. The absence of this phase affects the tie-line relations in the BaO-rich region of the phase diagram of the Yb-system. Furthermore, while the diagrams with relatively large R (i.e., $\text{R} = \text{Nd, Sm, Eu, Gd, Dy, Er}$) do not contain a tie-line between BaCuO_{2+z} and BaR_2CuO_5 , this tie-line was found in the Yb-diagram, which has a much smaller R. In general, both the diagrams of the $\text{BaO-Tm}_2\text{O}_3\text{-CuO}_z$ and of the $\text{BaO-Yb}_2\text{O}_3\text{-CuO}_z$ systems prepared under carbonate-free conditions are different from those obtained using BaCO_3 -derived starting materials.

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1. Introduction

Since the discovery of the high temperature superconductor oxides [1], considerable technological progress has been achieved in wire and tape development. Intensive research has led to the powder-in-tube (PIT) process for fabrication of Bi-Pb-Sr-Ca-Cu-O (BSCCO) tapes [2–6]. More recently, second-generation high- T_c superconductor (HTS) tapes (also called HTS coated conductors) deposited on flexible coated-conductors have received much attention [7–11]. Second-generation superconductors are based on $\text{Ba}_2\text{YCu}_3\text{O}_{6+z}$ and $\text{Ba}_2\text{RCu}_3\text{O}_{6+z}$ materials ($\text{R} = \text{lanthanide-substituted variants}$) [12–15]. The $\text{Ba}_2\text{YCu}_3\text{O}_{6+z}$ and $\text{Ba}_2\text{RCu}_3\text{O}_{6+z}$ materials are relatively more isotropic when compared with BSCCO-based superconductors, and can retain current-carrying ability at liquid nitrogen temperature under high magnetic fields. As a result, HTS coated-conductor have great commercial potential for elec-

tric utility and high magnetic field applications. The efforts of the Superconductivity Partnership Initiative of the US Department of Energy have led to a substantial number of prototype applications [16].

Two HTS coated-conductor processes are furthest along in their technological development: the rolling-assisted biaxially textured substrate process (RABiTS) [7–9], and the ion beam-assisted deposition process (IBAD) [10,11]. Phase diagrams provide important data for both processes. Previously, we have reported phase diagram studies of the $\text{BaO-R}_2\text{O}_3\text{-CuO}_z$ systems ($\text{R} = \text{Nd}$ [17], Sm [18], Y [19], Er , Gd [20], Dy , Ho and Eu [21]) under carbonate-free conditions at $p_{\text{O}_2} = 100$ Pa. The experimental conditions were selected to match RABiTS and IBAD processing conditions. Phase diagrams of the $\text{BaO-Tm}_2\text{O}_3\text{-CuO}_z$ [22,23] and $\text{BaO-Yb}_2\text{O}_3\text{-CuO}_z$ [24,25] systems are available in literature; however, partly because it is difficult to handle BaO, the majority of these diagrams were prepared using BaCO_3 as one of the starting reagents. The goal of the present paper is to report our studies of the $\text{R} = \text{Tm}$ and $\text{R} = \text{Yb}$ systems under conditions similar to our previous studies, i.e., $p_{\text{O}_2} = 100$ Pa, $T = 750$ °C and 810 °C, with BaO as a source

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Table 1

Samples prepared for the phase relationship studies in the BaO–Tm₂O₃–CuO_z and BaO–Yb₂O₃–CuO_z systems at $p_{O_2} = 100$ Pa, and $T = 750$ °C and 810 °C

No.	Ba	Tm/Yb	Cu	No.	Ba	Tm/Yb	Cu
1	60	10	30	2	50	17	33
3	65	17.5	17.5	4	70	5	25
5	58	3	39	6	42.86	57.14	0
7	54	8	38	7	45	15	40
9	40	40	20	9	60	35	5
11	40	20	40	12	35	60	5
13	20	70	10	14	25	25	50
15	40	5	55	16	25	5	70
17	10	35	55	18	10	65	25
19	50	25	25	20	45	10	45
21	35	53	12	22	50	40	10
23	35	20	45	24	33.33	16.67	50
25	32	18	50	26	63	3	34
27	50	12.5	37.5	28	33.33	66.67	0

In the table, Ba stands for BaO, Tm/Yb stands for 1/2(Tm₂O₃) or 1/2(Yb₂O₃), and Cu stands for CuO. The numbers in the table correspond to mole fraction, %.

for Ba. The crystal chemistry and crystal structure of compounds of the BaO–R₂O₃–CuO_z systems have been reported extensively in literature and will not be discussed in detail here. Emphasis will be placed on the phase formation and phase compatibilities, which are important for coated conductor processing.

2. Experimental details¹

2.1. Preparation of BaO

BaO starting material was produced from BaCO₃ (99.99% purity, metals basis) by vacuum calcination in a custom-designed vertical tube furnace. An MgO crucible containing ~15 g of BaCO₃ was suspended in the hot zone of the furnace, and the furnace was evacuated to a pressure of ~10 μmHg or less by a high capacity mechanical pump. The temperature of the sample was raised from room temperature to 1300 °C in 20 h, followed by an isothermal heat-treatment at 1300 °C for 10 h, and then cooled from 1300 °C to room temperature in 20 h. During vacuum calcination the pressure typically increased to ~200 μmHg as CO₂ was evolved, and then rapidly returned to ~10 μmHg or less as the decomposition of the BaCO₃ was completed. After cooling, the BaO was lowered through an interlock into a transfer vessel. It was then transported to an Ar-filled glove-box continually purged with a recirculating purifier, which removed atmospheric contaminants from the Ar to <1 ppm by volume. Characterization by X-ray powder diffraction showed only the characteristic peaks for BaO.

2.2. Sample preparation

All sample weighings, homogenizations and pressings of pellets were performed inside the glove-box to avoid contamination with CO₂ and H₂O. Pelletized samples were placed inside individual MgO crucibles for annealing in a horizontal box-type controlled-atmosphere furnace. Transfer from the glove-box to the box furnace and vice versa was achieved via a second transfer vessel and an interlock system attached to the furnace.

The solid-state sintering method was used to prepare 28 samples each for the BaO–Tm₂O₃–CuO_z system and for the BaO–Yb₂O₃–CuO_z system (Table 1). Stoichiometric amounts of BaO, R₂O₃ (R = Tm and Yb) (99.99% purity, metals basis), and CuO (99.99% purity, metals basis) were mixed and pressed into pellets,

and annealed in the box furnace. During the annealings, the oxygen pressure of Ar/O₂ mixtures was controlled using a mass flow meter and monitored at both the inlet and outlet of the furnace using a zirconia oxygen sensor. Samples were annealed at 750 °C and at 810 °C for the experiments at $p_{O_2} = 100$ Pa (0.1% O₂ by volume). Intermediate grindings and pelletizings took place until no further changes were detected in the powder X-ray diffraction patterns. Samples were processed for about 3 weeks each.

2.3. X-ray powder diffraction

For X-ray phase analysis, specimens were loaded into a hermetic cell designed for air-sensitive materials [26]. The process of sample loading was performed inside an Ar-filled glove-box. X-ray powder diffraction was used to identify the phases synthesized and to confirm phase purity. Data were collected using a computer-controlled automated diffractometer equipped with a theta-compensation slit; Cu Kα radiation was used at 45 kV and 40 mA. The radiation was detected by a scintillation counter and a solid-state amplifier. A Siemens diffraction software package and reference X-ray diffraction patterns of the ICDD Powder Diffraction File (PDF) [27] were used for phase identification.

3. Results and discussion

Figs. 1–4 give the phase diagrams of the BaO–Tm₂O₃–CuO_z and the BaO–Yb₂O₃–CuO_z systems. These diagrams appear to be relatively simple, but are different from those prepared using BaCO₃ [22–25], particularly in the Ba-rich region. Due to the substantially different ionic size of Tm³⁺ and Ba²⁺ (0.994 Å versus 1.42 Å), and Yb³⁺ and Ba²⁺ (0.985 Å versus 1.42 Å) [28], respectively, there is no detectable solid solution formation of compounds in these systems under the current experimental conditions.

3.1. Phase formation

3.1.1. BaO–Tm₂O₃–CuO_z system

3.1.1.1. The BaO–CuO_z System. A review of the crystal chemistry and crystallography of the phases in the BaO–CuO_z system was given by Wong-Ng and Cook [29], and therefore the details

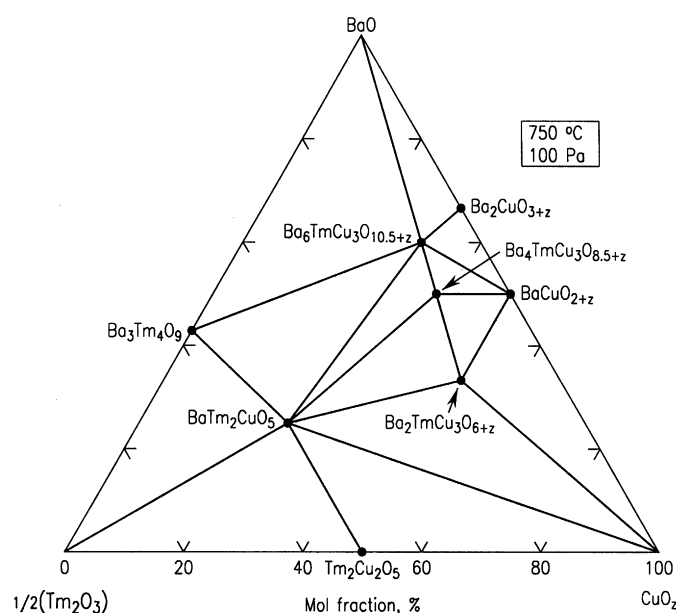


Fig. 1. Phase diagram of the BaO–1/2Tm₂O₃–CuO_z system prepared at $p_{O_2} = 100$ Pa and ≈ 750 °C, using BaO starting material.

¹ Certain commercial equipment, instruments, or materials are identified in this paper to foster understanding. Such identification does not imply recommendation or endorsement by the National Institute of Standards and Technology, nor does it imply that the materials or equipment identified are necessarily the best available for the purpose.

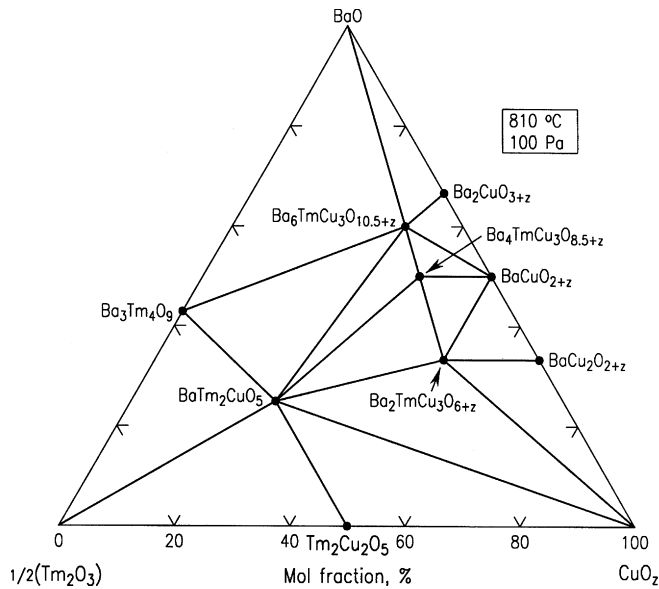


Fig. 2. Phase diagram of the BaO– $1/2\text{Tm}_2\text{O}_3$ – CuO_z system prepared at $p_{\text{O}_2} = 100$ Pa and $\approx 810^\circ\text{C}$, using BaO starting material.

will not be discussed here. At both 750°C and 810°C , the compounds $\text{Ba}_2\text{CuO}_{3+z}$ and BaCuO_{2+z} were found to be stable at $p_{\text{O}_2} = 100$ Pa [29–34]. The $\text{Ba}_2\text{CuO}_{3+z}$ phase is atmospherically sensitive, and cannot be prepared in the presence of moisture and carbonate. The oxygen content of the BaCuO_{2+z} series has been reported to vary between 2.0 and 2.5 [29]. Three structure types are known ($0 < z < 0.12$, $0.29 < z < 0.36$, and $z = 0.5$). The most commonly recognized structure form is cubic, with $0 < z < 0.12$. Phase compositions with z greater than 0.12 have been reported by Petricek et al. [34]. At 810°C , we found that the reduced phase $\text{BaCu}_2\text{O}_{2+z}$ was observed in addition to $\text{Ba}_2\text{CuO}_{3+z}$ and BaCuO_{2+z} . Also, CuO was found to be reduced to Cu_2O . There is no evidence for the existence of the $\text{Ba}_2\text{Cu}_3\text{O}_{5+z}$ or $\text{Ba}_3\text{Cu}_5\text{O}_{8+z}$

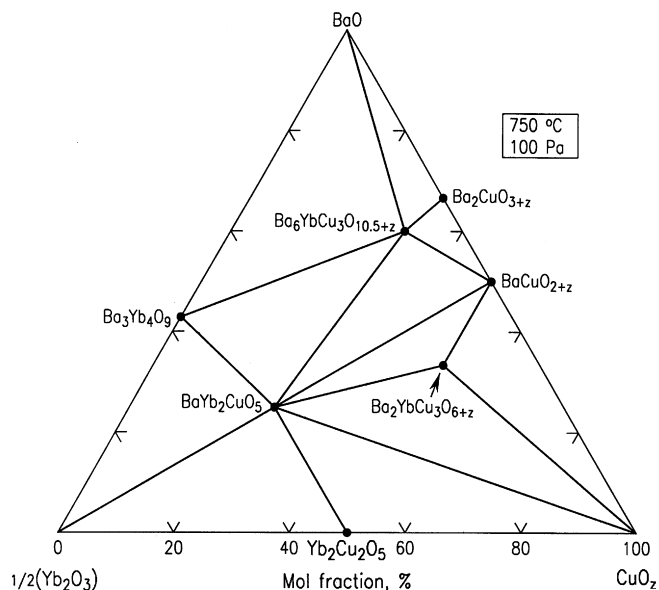


Fig. 3. Phase diagram of the BaO– $1/2\text{Yb}_2\text{O}_3$ – CuO_z system prepared at $p_{\text{O}_2} = 100$ Pa and $\approx 750^\circ\text{C}$, using BaO starting material.

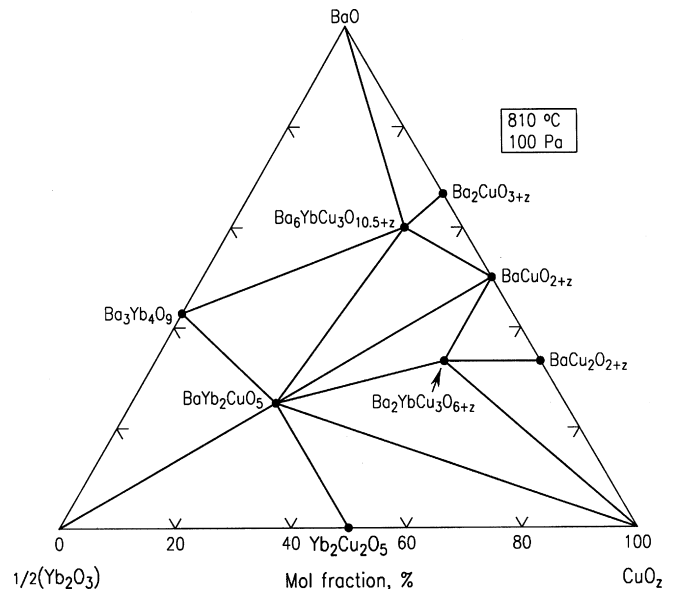


Fig. 4. Phase diagram of the BaO– $1/2\text{Yb}_2\text{O}_3$ – CuO_z system prepared at $p_{\text{O}_2} = 100$ Pa and $\approx 810^\circ\text{C}$, using BaO starting material.

phases [30]. The Ba_3CuO_4 phase, reported by Frase and Clarke [35] and Abbattista et al. [36,37] to be stable under very reduced conditions, was not detected in the present study. In contrast to the BaO– Nd_2O_3 – CuO_z [17], BaO– Sm_2O_3 – CuO_z [18], and the BaO– Eu_2O_3 – CuO_z [21] systems where one observes the formation of the $(\text{Ba}, \text{R})_2\text{CuO}_{3+z}$ phase, no solid solution formation of the $(\text{Ba}, \text{Tm})_2\text{CuO}_{3+z}$ system was found due to the large difference in the ionic size of Ba and Tm [28].

3.1.1.2. BaO– Tm_2O_3 . Different from the BaO– Y_2O_3 [19] and BaO– Er_2O_3 [20] systems, the $\text{Ba}_3\text{R}_4\text{O}_9$ but not BaR_2O_4 phase was found to be stable in the BaO– Tm_2O_3 system at both 750°C and 810°C . The $\text{Ba}_2\text{R}_2\text{O}_5$ and $\text{Ba}_4\text{R}_2\text{O}_9$ -type phases as reported in the BaO– Y_2O_3 – CuO_z system (prepared with BaCO_3 -derived starting materials [38]) are not stable here. The Y-analogs of these phases have been determined by Abbattista et al. [37] and DeLeeuw et al. [32] to correspond to $\text{Ba}_2\text{Y}_2\text{O}_5 \cdot \text{CO}_2$ and $\text{Ba}_4\text{Y}_2\text{O}_9 \cdot 2\text{CO}_2$.

3.1.1.3. Tm_2O_3 – CuO_z . At both 750°C and 810°C , only the $\text{Tm}_2\text{Cu}_2\text{O}_5$ phase was observed in the Tm_2O_3 – CuO_z diagram [39]. The R_2CuO_4 type phase only exists when R is relatively large ($r_{\text{R}^{3+}} > r_{\text{Dy}^{3+}}$). As $r_{\text{R}^{3+}}$ decreases beyond Gd (namely, from Dy to Lu), the $\text{R}_2\text{Cu}_2\text{O}_5$ type phase (orthorhombic, $\text{Pna}2_1$) was found instead of R_2CuO_4 [13]. Furthermore, the reported reduced phase of the YCuO_2 structure type [40,41] was not found; presumably the oxygen partial pressure of $p_{\text{O}_2} = 100$ Pa is not sufficiently low to stabilize this phase.

3.1.1.4. BaO– Tm_2O_3 – CuO_z . At both 750°C and 810°C , a total of four ternary oxides ($\text{Ba}_2\text{TmCu}_3\text{O}_{6+z}$, $\text{Ba}_4\text{TmCu}_3\text{O}_{8.5+z}$, $\text{Ba}_6\text{TmCu}_3\text{O}_{10.5+z}$, and the ‘green phase’ $\text{BaTm}_2\text{CuO}_5$) were found in the BaO– Tm_2O_3 – CuO_z system (Figs. 1 and 2). The formation of the compounds $\text{Ba}_4\text{RCu}_3\text{O}_{8.5+z}$ and $\text{Ba}_6\text{RCu}_3\text{O}_{10.5+z}$ in the BaO-rich part of the diagram is similar to that in the

BaO–Y₂O₃–CuO_z, BaO–Ho₂O₃–CuO_z and BaO–Er₂O₃–CuO_z systems [19–21,24]. The structure of Ba₄TmCu₃O_{8.5+z} was reported to be of the cubic oxygen-defect perovskite type ($a = 8.07670(8) \text{ \AA}$ when prepared in oxygen) [42,43]. The orthorhombic Ba₆TmCu₃O_{10.5+z} phase is of the SrTi₂O₄-type (layered perovskite structure) [44]. The structure of the BaTm₂CuO₅ “green” phase (orthorhombic with space group *Pnma*), has been studied extensively [13,45–47]. This phase, however, has a different structure from that of the Nd-brown phase (BaNd₂CuO₅) [17].

Similar to the Ba₂RCu₃O_{6+z} analogs (R = Y, Er, Ho), Ba₂TmCu₃O_{6+z} is a stoichiometric compound with respect to the cation content. By contrast, solid solution formation was reported in the lanthanide-containing Ba_{2–x}R_{1+x}Cu₃O_{6+z} phases with relatively larger size of R (for example, R = Nd³⁺ (1.109 Å), Sm³⁺ (1.079 Å), and Eu³⁺ (1.004 Å)) [28] when samples were also prepared under 100 Pa [17,18,21].

3.1.2. BaO–Yb₂O₃–CuO_z system

The phases determined in the BaO–CuO_z system, namely, Ba₂CuO_{3+z}, BaCuO_{2+z} (under both 750 °C and 810 °C), and an additional BaCu₂O_{2+z} phase while the diagram was prepared under 810 °C have already been discussed above.

3.1.2.1. BaO–Yb₂O₃. The binary diagram of the BaO–Yb₂O₃ system was reported by Lopato et al. [48]. Under both 750 °C and 810 °C (Figs. 3 and 4), the Ba₃Yb₄O₉ phase was the only compound found in the binary BaO–Yb₂O₃ system. Ba₃Yb₄O₉ was reported to crystallize in the rhombohedral *R* $\bar{3}m$ system [49], which is isostructural with the Ba₃Tm₄O₉ and Ba₃Y₄O₉ structure [19]. The BaR₂O₄ type phase (orthorhombic *Pnam*) which exists in systems with larger R³⁺ (for example, R = Ho, Y, Er, etc.) [50] cannot be prepared with the relatively small Yb³⁺. Similar to the Tm-analog, the Ba₄R₂O₇ and Ba₂R₂O₅ phases which were reported when BaCO₃ was used as a starting reagent, were found to be absent under carbonate-free conditions.

3.1.2.2. Yb₂O₃–CuO_z. The phase diagram of the Yb₂O₃–CuO_z system prepared in air was reported by Chen et al. [51]. Similar to the Tm-analog, only the Yb₂Cu₂O₅ phase was obtained under 750 °C and 810 °C. Neither the Yb₂CuO₄ type phase nor the rhombohedral YbCuO₂ (RCuO₂ structure type [40,41]) was found.

3.1.2.3. BaO–Yb₂O₃–CuO_z. There are a total of three ternary oxide phases in the BaO–Yb₂O₃–CuO_z system, namely, Ba₂YbCu₃O_{6+z}, BaYb₂CuO₅, and Ba₆YbCu₃O_{10.5+z}. Due to the great mismatch of the size of Yb³⁺ and Ba²⁺ (0.985 Å versus 1.42 Å) [28], solid solution formation was not found in this system. Our results agree with those of Osamura and Zhang [24] in that in the temperature range of 750–810 °C, the Ba₂YbCu₃O_{6+z} phase is stable at oxygen partial pressures below approximately 10⁴ Pa. At higher temperatures, a mixture of BaYb₂CuO₅, BaCuO_{2+z}, and CuO was obtained instead. The Ba₆YbCu₃O_{10.5+z} phase was reported by Zhang and Osamura to be perovskite-related [44]. Similar to the Ba₆ErCu₃O_{10.5+z}, Ba₆YCu₃O_{10.5+z}, and Ba₆HoCu₃O_{10.5+z}

phases [19], Ba₆YbCu₃O_{10.5+z} was reported to be orthorhombic (*Immm*, $a = 3.9830(2) \text{ \AA}$, $b = 4.0986(2) \text{ \AA}$, and $c = 21.571(1) \text{ \AA}$) when prepared in air [44]. While the Ba₄YbCu₃O_{8.5+z} phase can be prepared at $p_{\text{O}_2} = 0.1 \text{ MPa}$ or $p_{\text{O}_2} = 0.022 \text{ MPa}$ (air) [44,52], it cannot be prepared at $p_{\text{O}_2} = 100 \text{ Pa}$. The ‘green phase’ BaYb₂CuO₅ is isostructural to BaTm₂CuO₅ [13].

3.2. Phase Compatibilities

3.2.1. BaO–Tm₂O₃–CuO_z

The tie-lines determined near the CuO_z and Tm₂O₃ regions are in agreement with those determined in most other BaO–R₂O₃–CuO_z diagrams, whether prepared using BaCO₃, BaO₂, BaO, or Ba(NO₃)₂. However, the BaO-rich regions of the diagrams are substantially different from each other. This diagram of the Tm-system prepared using BaO is somewhat different to that of the BaO–Y₂O₃–CuO_z system reported by us [19]. The tie-line relationships around the 213 phase which involve the four phases, Ba₂TmCu₃O_{6+z}, BaTm₂CuO₅, BaCuO_{2+z}, and Ba₄TmCu₃O_z are also different from the literature data. For example, in the present study, the Ba₂TmCu₃O_{6+z} phase is found to be compatible to the Ba₄TmCu₃O_z phase, whereas most literature phase diagrams of the BaO–R₂O₃–CuO_z systems involve a tie-line between BaCuO_{2+z} and BaR₂CuO₅ [13,19,22,23,53–58]. The Ba₂RCu₃O_{6+z}–Ba₄RCu₃O_z tie-line was also found in our previous studies of the Nd-, Sm-, Eu, Dy-, Ho-, Y-, and Er-systems [17–21], and during the investigation of the melting equilibria of the BaO–Y₂O₃–CuO_z system [59]. The majority of literature studies were not conducted entirely under atmospherically-controlled conditions, and it is clear that the presence of CO₂ affects the tie-line relationships.

3.2.2. BaO–Yb₂O₃–CuO_z

The tie-line distribution in the Ba-poor region of the BaO–Yb₂O₃–CuO_z system, as shown in Figs. 3 and 4, is in general similar to that found in the BaO–Tm₂O₃–CuO_z system. Unexpectedly, we found that at both 750 °C and 810 °C, there is a tie-line connecting the BaCuO_{2+z} phase to the ‘green phase’, BaYb₂CuO₅. This is different from other BaO–R₂O₃–CuO_z systems while the size of R³⁺ is larger than that of Yb³⁺. Therefore, whether a tie-line exists between BaR₂CuO₅ and BaCuO_{2+z}, or between Ba₂RCu₃O_{6+z} and a barium-rich phase appears to depend on the condition of preparation and the size of R³⁺. A comparison of the BaO–Yb₂O₃–CuO_z diagrams (Figs. 1 and 2) to the BaO–Tm₂O₃–CuO_z diagrams (Figs. 3 and 4) indicates that the absence of the Ba₄YbCu₃O_{8.5+z} phase affects the tie-line relations in the region bounded by BaCuO₂, Ba₂YbCu₃O_{6+z}, BaYb₂CuO₅, and Ba₆YbCu₃O_{10.5+z}. All ternary oxides are compatible with at least four other phases. In the case of BaYb₂CuO₅, seven tie-lines were found to originate from it. In the BaO-rich region, tie-lines are found between BaO and Ba₆YbCu₃O_z.

3.2.3. Implications for processing

For applications of phase equilibria to coated conductor processing, phase diagrams constructed under carbonate-free conditions should be employed. An examination of Figs. 1–4

shows a significant difference in the tie-line distributions occurring under carbonate-free conditions, relative to those occurring in the phase diagrams based on BaCO₃-derived starting materials [22–25]. Under carbonate-free conditions at a p_{O_2} of 100 Pa, the Ba₂TmCu₃O_{6+z}–Ba₄TmCu₃O_z tie-line replaces a BaCuO_{2+z}–BaTm₂CuO₅ tie-line in the BaO–Tm₂O₃–CuO_z system; and a BaCuO_{2+z}–BaYb₂CuO₅ tie-line replaces the Ba₂YbCu₃O_{6+z}–Ba₆YbCu₃O_z tie-line in the BaO–Yb₂O₃–CuO_z system. The net effect of this difference is that in the Tm-case, there is an expansion of the field of stability of Tm-213 towards the BaO-rich corner of the phase diagram as compared to the Yb-213 phase; Ba₄TmCu₃O_{8.5+z} can coexist with Tm-213. However, because Ba₄RCu₃O_{8.5+z} is atmospherically more sensitive than BaR₂CuO₅, its presence in R-213 materials could be deleterious. It may be important during the RABiTS and IBAD processes to avoid bulk compositions in this region.

4. Summary

We have investigated the phase relationships of the BaO–Tm₂O₃–CuO_z and the BaO–Yb₂O₃–CuO_z systems at $p_{O_2} = 100$ Pa under both 750 °C and 810 °C. Sample preparation and handling were accomplished using a glove-box filled with argon and an atmospherically-controlled furnace and apparatus. Similar to the Nd-, Sm-, Eu-, Gd-, Dy-, Ho-, Y-, and Er-systems that we have reported previously [17–21], the presence of CO₂ affects the tie-line relationships. For example, the tie-line relationships among the four phases, BaTm₂CuO₅, Ba₂TmCu₃O_z, BaCuO_{2+z}, and Ba₄TmCu₃O_{8.5+z} are different from the literature data. A tie-line between Ba₂TmCu₃O_z and Ba₄TmCu₃O_{8.5+z} was observed. In the Yb-system, a tie-line between BaYb₂CuO₅ and BaCuO_{2+z} was found instead. It appears that whether a tie-line exists between BaR₂CuO₅ and BaCuO_{2+z}, or between Ba₂RCu₃O_{6+z} and a barium-rich phase appears to depend on the condition of preparation and the size of R³⁺. In addition, due to the absence of the Ba₄YbCu₃O_{8.5+z} phase in the Yb-analog, the tie-line relations are different in the BaO–Yb₂O₃–CuO_z and the BaO–Tm₂O₃–CuO_z systems.

Phase diagrams of the BaO–R₂O₃–CuO_z (R = lanthanides) systems are important for coated-conductor development, and it is anticipated that systematic studies of diagrams of these systems under relevant atmospherically-controlled conditions will continue.

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